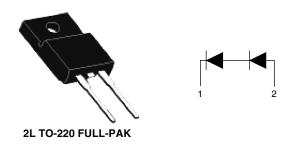
COMPLIANT HALOGEN

FREE



Vishay Semiconductors

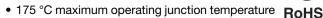
Hyperfast Rectifier, 8 A FRED Pt®



PRODUCT SUMMARY					
Package	2L TO-220FP				
I _{F(AV)}	8 A				
V_{R}	600 V				
V _F at I _F	2.4 V				
t _{rr} (typ.)	See Recovery table				
T _J max.	175 °C				
Diode variation	Doubler				

FEATURES





• High frequency PFC CCM operation

Trigit frequency 110 00M operation

Low leakage current

• Halogen-free according to IEC 61249-2-21 definition

• Designed and qualified for industrial level

DESCRIPTION

VS-8S2TH06FP 600 V series are the state of the art tandem hyperfast recovery rectifiers: excellent switching performance and extremely low forward voltage drop trade off is overcome, boosting overall application performance. Specially designed for CCM PFC application, these devices show incomparable performance in every current intensive hard switching application.

Optimized reverse recovery stored charge enables downsizing of boosting switch and cooling system, increased operating frequency make possible use of smaller reactive elements. Cost effective PFC application is then possible with high efficiency over wide input voltage range and loading factor.

Plastic insulated package features easy mounting together with not insulated parts.

ABSOLUTE MAXIMUM RATINGS FOR BOTH DIODES						
PARAMETER	SYMBOL TEST CONDITIONS		MAX.	UNITS		
Repetitive peak reverse voltage	V_{RRM}		600	V		
DC forward current	I _F	50 % duty cycle, rect. waveforms, $T_C = 93$ °C	8	^		
Non-repetitive peak surge current	I _{FSM}	T _C = 25 °C	100	A		
Operating junction and storage temperatures	T _J , T _{Stg}		- 55 to 175	°C		

ELECTRICAL SPECIFICATIONS FOR BOTH DIODES (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Forward voltage V _F	I _F = 8 A	-	2.1	2.4	V		
	V_{F}	I _F = 8 A, T _J = 125 °C	-	1.7	2		
	I _F = 8 A, T _J = 150 °C	-	1.6	1.8			
		V _R = V _R rated	-	< 1	10		
Reverse leakage current I _R	I _R	$T_J = 125 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	7	80	μA	
	T _J = 150 °C, V _R = V _R rated	-	27	100			
Junction capacitance	C _T	V _R = 600 V	-	12	-	pF	

VS-8S2TH06FP

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DYNAMIC RECOVERY CHARACTERISTICS FOR BOTH DIODES (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt = -50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	-	25	
Reverse recovery time		$T_J = 25 ^{\circ}C$	I _F = 8 A	-	19	-	ns
		T _J = 125 °C		-	35	-	
Peak recovery current I _{RRM}		T _J = 25 °C		-	2.8	-	۸
	T _J = 125 °C	dl _F /dt = - 200 A/µs V _R = 390 V	=	4.6	5.5	А	
Reverse recovery charge Q _{rr}	Q _{rr}	T _J = 25 °C		-	26	-	nC
		T _J = 125 °C		-	84	-	IIC

THERMAL - MECHANICAL SPECIFICATIONS FOR BOTH DIODES						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55	-	175	°C
Thermal resistance, junction to case	R _{thJC}		-	4.1	4.8	°C/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	C/VV
Weight			-	2.0	-	g
vveignt			-	0.07	-	OZ.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style 2L TO-220 FULL-PAK	8S2TH06FP			



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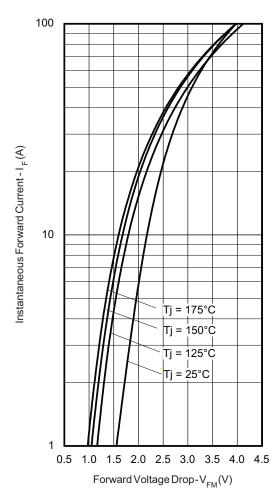


Fig. 1 - Maximum Forward Voltage Drop Characteristics

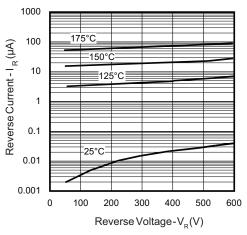


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

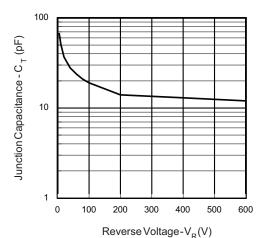


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

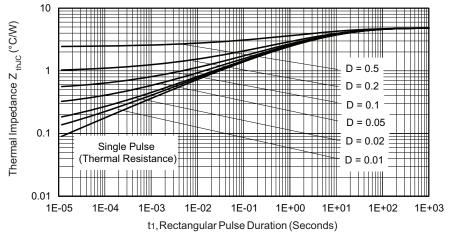


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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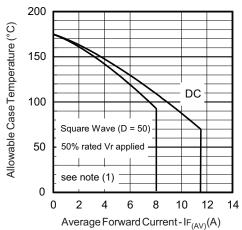


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

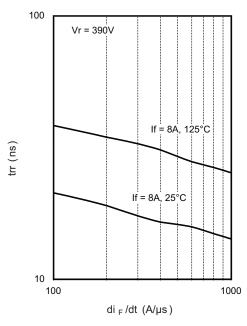


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

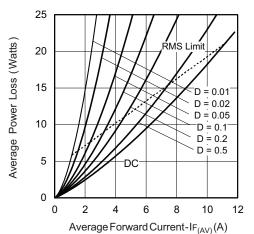


Fig. 6 - Forward Power Loss Characteristics

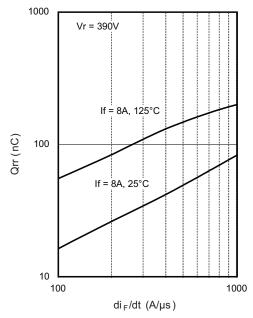


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

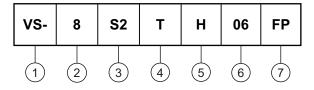
 $^{(1)}$ Formula used: T_C = T_J - (Pd +Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 50 % rated V_R



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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product suffix

2 - Current rating (8 = 8 A)

3 - S2 = Doubler true 2 pin

4 - T = TO-220

5 - H = Hyperfast recovery

- Voltage rating (06 = 600 V)

7 - FP = TO-220 FULL-PAK

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95263</u>					
Part marking information	www.vishay.com/doc?95265				



Vishay

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